



YOUSHANG SEMICONDUCTOR

**设计研发新型功率器件**

**各类小信号开关**

**中低压及高压大电流等场效应管**

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### Features

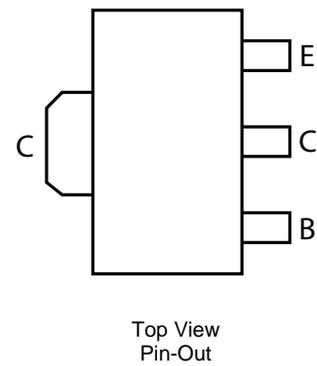
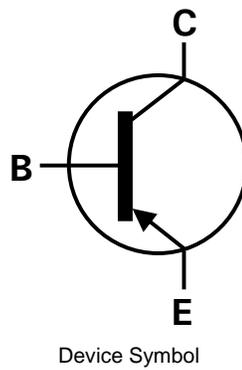
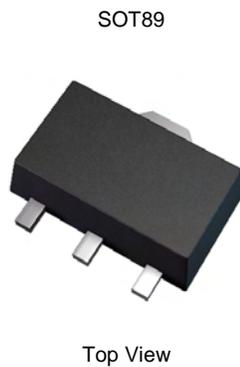
- $BV_{CEO} > -100V$
- Maximum continuous current  $I_C = -1A$
- $h_{FE} > 100$  @  $I_C = -150mA$ ,  $V_{CE} = -0.2V$

### Applications

- LED TV backlight

### Mechanical Data

- Case: SOT89
- Case material: molded Plastic. "Green" molding Compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.052 grams (Approximate)



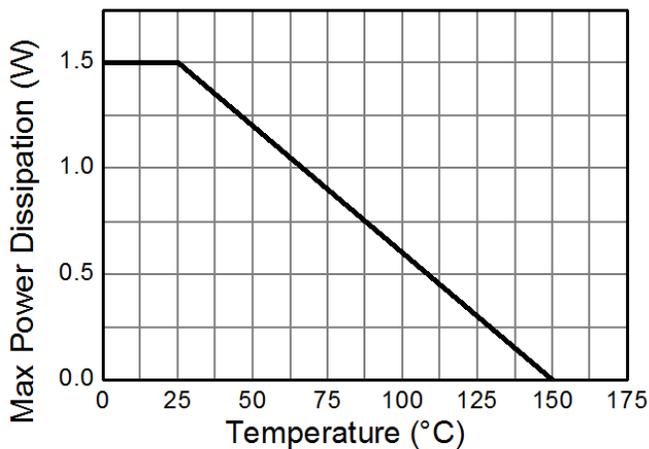
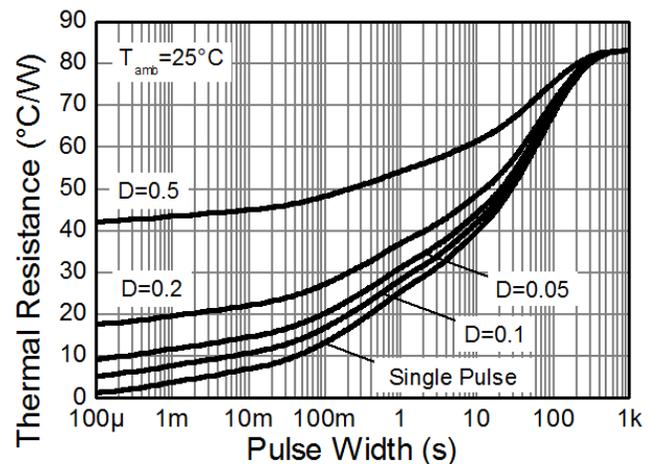
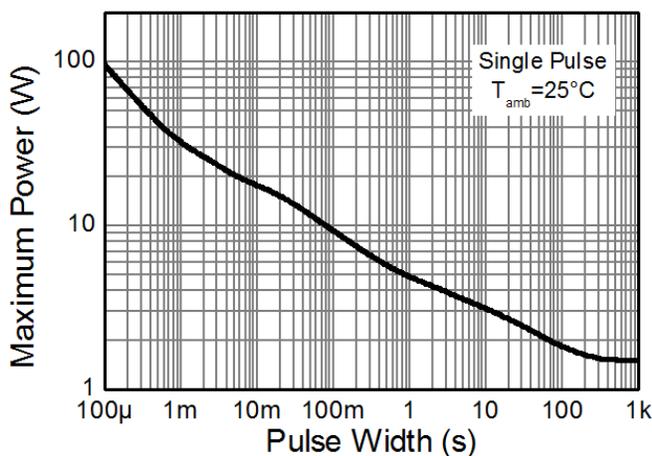
**Maximum Ratings** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CB0}$	-100	V
Collector-Emitter Voltage	$V_{CEO}$	-100	V
Emitter-Base Voltage	$V_{EBO}$	-7	V
Continuous Collector Current	$I_C$	-1	A
Peak Pulse Current (Note 4)	$I_{CM}$	-3	A
Base Current	$I_B$	-500	mA

**Thermal Characteristics** @ $T_A = 25^\circ\text{C}$  unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	$P_D$	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	83	$^\circ\text{C/W}$
Thermal Resistance, Junction to Leads (Note 6)	$R_{\theta JL}$	17.46	$^\circ\text{C/W}$
Operating and Storage Temperature Range	$T_J, T_{STG}$	-55 to +150	$^\circ\text{C}$

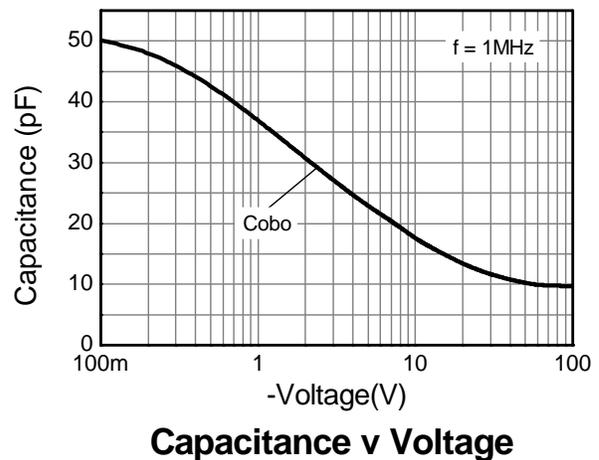
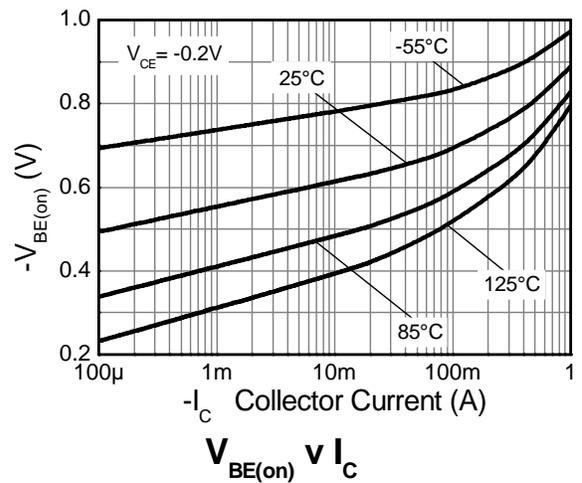
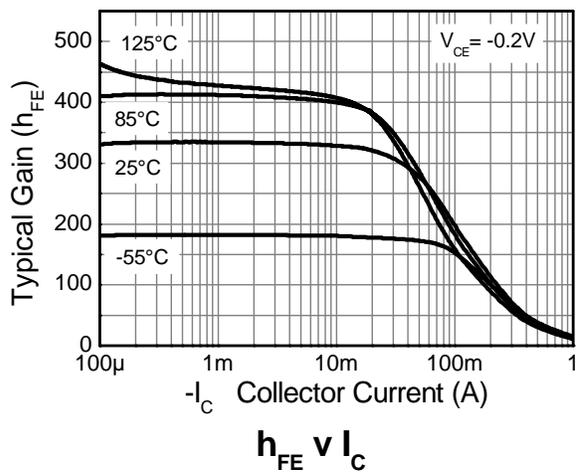
- Notes:
4. Measured under pulsed conditions. Pulse width = 300 $\mu\text{s}$ . Duty cycle  $\leq 2\%$ .
  5. For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions
  6. Thermal resistance from junction to solder-point (on the exposed collector pad).

**Thermal Characteristics and Derating Information**

**Derating Curve**

**Transient Thermal Impedance**

**Pulse Power Dissipation**

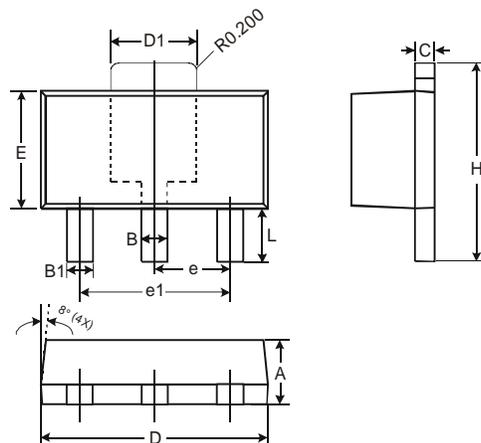
**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage (Note 7)	BV <sub>CEO</sub>	-100	-170	-	V	I <sub>C</sub> = -10mA
Collector Cut-off Current	I <sub>CBO</sub>	-	-	-50	nA	V <sub>CB</sub> = -100V
Emitter Cut-off Current	I <sub>EBO</sub>	-	-	-50	nA	V <sub>EB</sub> = -7V
Static Forward Current Transfer Ratio (Note 7)	h <sub>FE</sub>	60 100	133 112	-	-	I <sub>C</sub> = -85mA, V <sub>CE</sub> = -0.15V I <sub>C</sub> = -150mA, V <sub>CE</sub> = -0.2V
Base-Emitter Turn-On Voltage (Note 7)	V <sub>BE(on)</sub>	-	-0.71	-0.95	V	I <sub>C</sub> = -150mA, V <sub>CE</sub> = -0.2V
Delay Time	t <sub>(d)</sub>	-	378	-	ns	V <sub>CC</sub> = -80V, I <sub>C</sub> = -150mA, f -I <sub>B2</sub> = 1.5mA, V <sub>CE(ON)</sub> = -0.2V
Rise Time	t <sub>(r)</sub>	-	388	-	ns	
Storage Time	t <sub>(s)</sub>	-	1348	-	ns	
Fall Time	t <sub>(f)</sub>	-	382	-	ns	V <sub>CC</sub> = -80V, I <sub>C</sub> = -150mA, -I <sub>B2</sub> = -1.5mA, V <sub>CE(ON)</sub> = -4V
Storage Time	t <sub>(s)</sub>	-	75	-	ns	
Fall Time	t <sub>(f)</sub>	-	363	-	ns	

Notes: 7. Measured under pulsed conditions. Pulse width = 300μs. Duty cycle ≤ 2%

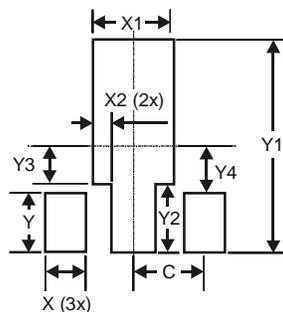
**Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified


## Package Outline Dimensions



SOT89		
Dim	Min	Max
A	1.40	1.60
B	0.44	0.62
B1	0.35	0.54
C	0.35	0.43
D	4.40	4.60
D1	1.52	1.83
E	2.29	2.60
e	1.50 Typ	
e1	3.00 Typ	
H	3.94	4.25
L	0.89	1.20
All Dimensions in mm		

## Suggested Pad Layout



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
C	1.500